July 2003

SL9R460P2, ISL9R460S2, ISL9R460S3S

## FAIRCHILD

SEMICONDUCTOR®

# ISL9R460P2, ISL9R460S2, ISL9R460S3S

### 4A, 600V Stealth<sup>™</sup> Diode

### **General Description**

The ISL9R460P2, ISL9R460S2 and ISL9R460S3S are Stealth<sup>™</sup> diodes optimized for low loss performance in high frequency hard switched applications. The Stealth<sup>™</sup> family exhibits low reverse recovery current (I<sub>RRM</sub>) and exceptionally soft recovery under typical operating conditions.

This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low  $I_{RRM}$  and short  $t_a$  phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the Stealth<sup>TM</sup> diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

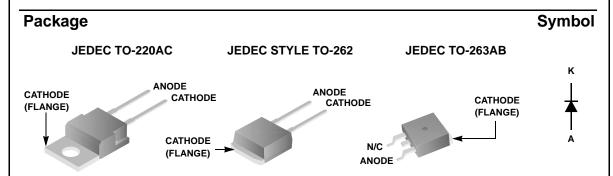
### Features

- Fast Recovery ......t<sub>rr</sub> < 20ns
- Avalanche Energy Rated

### Applications

- Switch Mode Power Supplies
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode

Formerly developmental type TA49408.

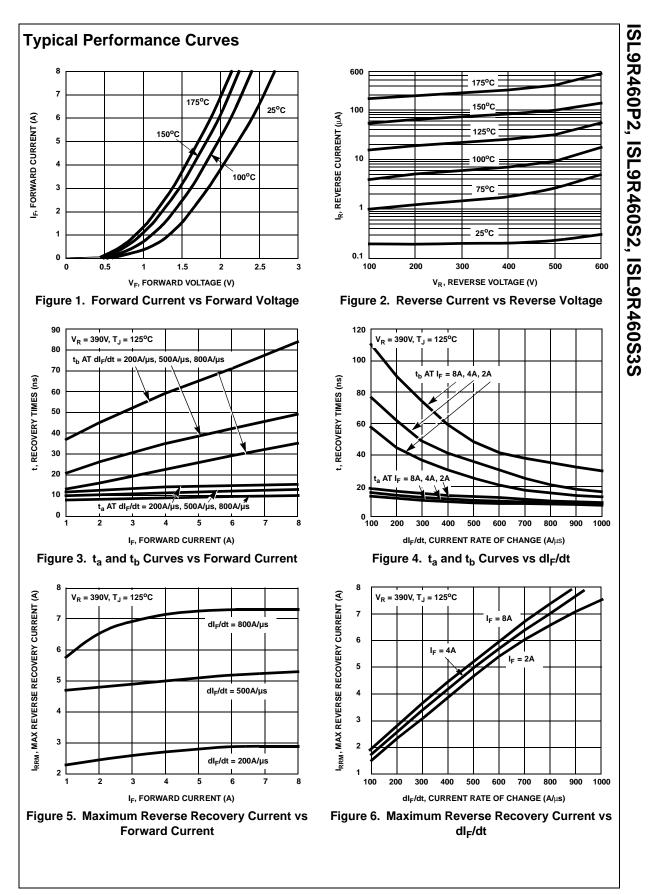


### Device Maximum Ratings T<sub>C</sub>= 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	600	V
V <sub>RWM</sub>	Working Peak Reverse Voltage	600	V
V <sub>R</sub>	DC Blocking Voltage	600	V
I <sub>F(AV)</sub>	Average Rectified Forward Current (T <sub>C</sub> = 155°C)	4	А
I <sub>FRM</sub>	Repetitive Peak Surge Current (20kHz Square Wave)	8	А
I <sub>FSM</sub>	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	50	А
PD	Power Dissipation	58	W
E <sub>AVL</sub>	Avalanche Energy (0.5A, 80mH)	10	mJ
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-55 to 175	°C
ΤL	Maximum Temperature for Soldering		
T <sub>PKG</sub>	Leads at 0.063in (1.6mm) from Case for 10s	300	°C
	Package Body for 10s, See Techbrief TB334	260	°C

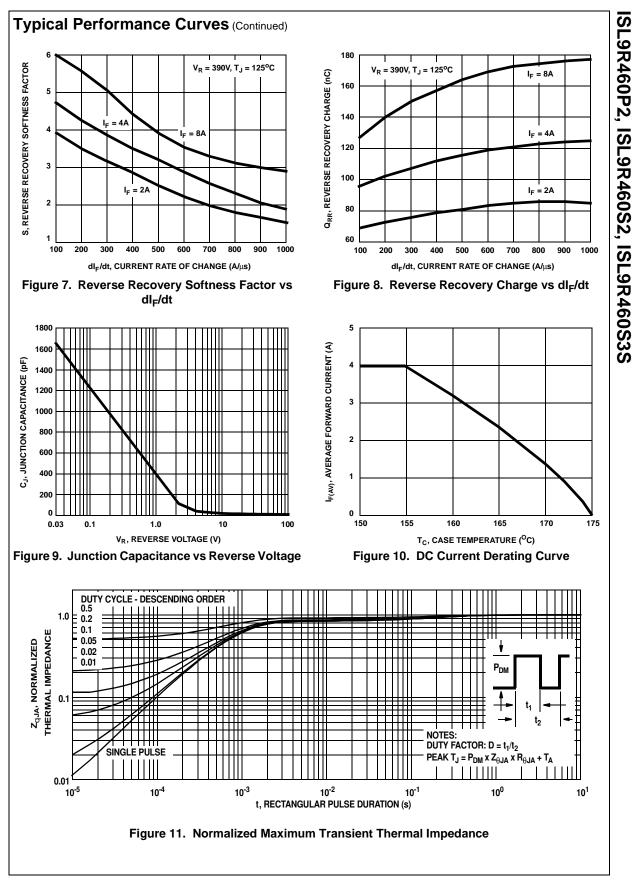
R46	Marking	Device	Package	Package Tape Widt			Quan	tity
			TO-220AC	N/A			50	
R46	60S2	ISL9R460S2	TO-262	N/A			50	
R46	0S3S	ISL9R460S3S	TO-263AB	N/A			50	
		TO-263AB	24mm			800		
lectric	al Char	<b>acteristics</b> T <sub>C</sub> = 25°C u	nless otherwise	noted				
Symbol Parameter		Test	Test Conditions		Тур	Max	Units	
ff State	Charact	eristics						
I <sub>R</sub>	Instantaneous Reverse Current		V <sub>R</sub> = 600V	$T_{C} = 25^{\circ}C$	-	-	100	μA
				T <sub>C</sub> = 125°C	-	-	1.0	mA
n State	Characte	aristics	l					
V <sub>F</sub>	1	ous Forward Voltage	I <sub>F</sub> = 4A	T <sub>C</sub> = 25°C	-	2.0	2.4	V
- r'				$T_{\rm C} = 125^{\circ}{\rm C}$	-	1.6	2.0	v
Inamir	Charact	oristics	1	0	1	1 -	1 -	1
					1	10		
CJ	Junction C	apacitance	$V_{R} = 10V, I_{F} = 0$	JA	-	19	-	pF
witchin	g Charac	teristics						
	-	teristics ecovery Time	I <sub>F</sub> = 1A, d <sub>IF</sub> /dt =	100A/µs, V <sub>B</sub> = 30V	-	17	20	ns
witchin <sup>t</sup> rr	-			100A/μs, V <sub>R</sub> = 30V 100A/μs, V <sub>R</sub> = 30V	-	17 19	20 22	ns ns
t <sub>rr</sub>	Reverse R			100A/μs, V <sub>R</sub> = 30V 100A/μs, V <sub>R</sub> = 30V				
t <sub>rr</sub> t <sub>rr</sub>	Reverse R Reverse R	ecovery Time	$I_F = 4A, d_{IF}/dt =$ $I_F = 4A, d_{IF}/dt = 200A/\mu s$	$100A/\mu s, V_{R} = 30V$		19		ns
t <sub>rr</sub> t <sub>rr</sub> I <sub>RRM</sub>	Reverse R Reverse R Maximum	ecovery Time ecovery Time	$I_F = 4A, d_{IF}/dt =$ $I_F = 4A,$	$100A/\mu s, V_{R} = 30V$	-	19 17		ns ns
t <sub>rr</sub> t <sub>rr</sub> I <sub>RRM</sub> Q <sub>RR</sub>	Reverse R Reverse R Maximum Reverse R	ecovery Time ecovery Time Reverse Recovery Current	$\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	-	19 17 2.6		ns ns A
t <sub>rr</sub> t <sub>rr</sub> I <sub>RRM</sub>	Reverse R Reverse R Maximum Reverse R Reverse R	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge	$\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt &= 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt &= 200A/\mu s \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	-	19 17 2.6 22		ns ns A nC
t <sub>rr</sub> I <sub>RRM</sub> Q <sub>RR</sub> t <sub>rr</sub>	Reverse R Reverse R Maximum Reverse R Reverse R Softness F	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time	$\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	-	19 17 2.6 22 77		ns ns A nC
t <sub>rr</sub> I <sub>RRM</sub> Q <sub>RR</sub> t <sub>rr</sub> S I <sub>RRM</sub>	Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t <sub>b</sub> /t <sub>a</sub> )	$\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt &= 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt &= 200A/\mu s \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C		19 17 2.6 22 77 4.2		ns ns A nC ns
t <sub>rr</sub> I <sub>RRM</sub> Q <sub>RR</sub> t <sub>rr</sub> S	Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t <sub>b</sub> /t <sub>a</sub> ) Reverse Recovery Current	$\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C		19 17 2.6 22 77 4.2 2.8		ns ns A nC ns A
t <sub>rr</sub> I <sub>RRM</sub> Q <sub>RR</sub> t <sub>rr</sub> S I <sub>RRM</sub> Q <sub>RR</sub>	Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t <sub>b</sub> /t <sub>a</sub> ) Reverse Recovery Current ecovery Charge	$\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C		19         17         2.6         22         77         4.2         2.8         100		ns ns A nC ns A nC
$t_{rr}$ $t_{rr}$ $I_{RRM}$ $Q_{RR}$ $t_{rr}$ $S$ $I_{RRM}$ $Q_{RR}$ $t_{rr}$ $S$ $I_{rr}$ $S$ $I_{rr}$ $S$ $I_{rr}$ $S$	Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor (t <sub>b</sub> /t <sub>a</sub> ) Reverse Recovery Current ecovery Charge ecovery Time	$\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \\ &V_{R} = 390V, \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	- - - - - - - - -	19           17           2.6           22           77           4.2           2.8           100           54		ns ns A nC ns A nC
$\begin{array}{c}t_{rr}\\ I_{RRM}\\ Q_{RR}\\ t_{rr}\\ S\\ I_{RRM}\\ Q_{RR}\\ t_{rr}\\ S\\ S\\ I_{RRM}\\ R_{RR}\\ M\\ R_{RR}\\ M\end{array}$	Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$	$\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	- - - - - - - - -	19           17           2.6           22           77           4.2           2.8           100           54           3.5		ns ns A nC ns A nC ns
t <sub>rr</sub> I <sub>RRM</sub> Q <sub>RR</sub> t <sub>rr</sub> S I <sub>RRM</sub> Q <sub>RR</sub> t <sub>rr</sub> S I <sub>RRM</sub> Q <sub>RR</sub>	Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Softness F Maximum Reverse R	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current	$\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \\ &V_{R} = 390V, \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	- - - - - - - - -	19           17           2.6           22           77           4.2           2.8           100           54           3.5           4.3		ns ns A nC ns A nC ns A A nC
$\begin{array}{c} t_{rr} \\ I_{RRM} \\ Q_{RR} \\ t_{rr} \\ S \\ I_{RRM} \\ Q_{RR} \\ t_{rr} \\ S \\ I_{RRM} \\ Q_{RR} \\ dI_{M}/dt \end{array}$	Reverse R Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Softness F Maximum Reverse R Maximum	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge di/dt during $t_b$	$\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \\ &V_{R} = 390V, \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	- - - - - - - - -	19           17           2.6           22           77           4.2           2.8           100           54           3.5           4.3           110	22 - - - - - - - - - - - -	ns ns A nC ns A nC ns A
$\begin{array}{c} t_{rr} \\ \hline t_{rr} \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline t_{rr} \\ \hline S \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline t_{rr} \\ \hline S \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline dl_{M}/dt \\ \hline \textbf{permal} \end{array}$	Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Softness F Maximum Reverse R Maximum Reverse R	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge di/dt during $t_b$	$\begin{split} &I_{F} = 4A, \ d_{IF}/dt = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \ T_{C} = \\ &I_{F} = 4A, \\ &d_{IF}/dt = 200A/\mu s \\ &V_{R} = 390V, \\ &T_{C} = 125^{\circ}C \\ &I_{F} = 4A, \\ &d_{IF}/dt = 400A/\mu s \\ &V_{R} = 390V, \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	- - - - - - - - -	19           17           2.6           22           77           4.2           2.8           100           54           3.5           4.3           110	22 - - - - - - - - - - - -	ns ns A nC ns A nC ns A A/µs
$\begin{array}{c} t_{rr} \\ \hline t_{rr} \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline t_{rr} \\ \hline S \\ \hline l_{RRM} \\ \hline Q_{RR} \\ \hline t_{rr} \\ \hline S \\ \hline \\ B_{RRM} \\ \hline Q_{RR} \\ \hline dI_{M}/dt \\ \hline \end{array}$	Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum Reverse R Maximum Reverse R Maximum Reverse R Maximum Reverse R	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge di/dt during $t_b$	$\begin{split} I_{F} &= 4A, \ d_{IF}/dt = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \ T_{C} = \\ I_{F} &= 4A, \\ d_{IF}/dt = 200A/\mu s \\ V_{R} &= 390V, \\ T_{C} &= 125^{\circ}C \\ I_{F} &= 4A, \\ d_{IF}/dt &= 400A/\mu s \\ V_{R} &= 390V, \\ T_{C} &= 125^{\circ}C \\ \end{split}$	100A/μs, V <sub>R</sub> = 30V s, = 25°C	- - - - - - - - -	19           17           2.6           22           77           4.2           2.8           100           54           3.5           4.3           110           500	22 - - - - - - - - - - - - - -	ns ns A nC ns A nC ns A Λ/μs
$\begin{array}{c} t_{rr} \\ I_{RRM} \\ Q_{RR} \\ t_{rr} \\ S \\ I_{RRM} \\ Q_{RR} \\ t_{rr} \\ S \\ I_{RRM} \\ Q_{RR} \\ dI_{M}/dt \\ \textbf{hermal} \end{array}$	Reverse R Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum Reverse R Maximum Reverse R Maximum Reverse R Maximum Reverse R Maximum Reverse R Maximum	ecovery Time ecovery Time Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge ecovery Time actor $(t_b/t_a)$ Reverse Recovery Current ecovery Charge di/dt during $t_b$ eristics esistance Junction to Case	$\begin{split} & I_{F} = 4A, \ d_{IF}/dt = \\ & I_{F} = 4A, \\ & d_{IF}/dt = 200A/\mu s \\ & V_{R} = 390V, \ T_{C} = \\ & I_{F} = 4A, \\ & d_{IF}/dt = 200A/\mu s \\ & V_{R} = 390V, \\ & T_{C} = 125^{\circ}C \\ & I_{F} = 4A, \\ & d_{IF}/dt = 400A/\mu s \\ & V_{R} = 390V, \\ & T_{C} = 125^{\circ}C \\ & \\ & \\ & T_{C} = 125^{\circ}C \\ & \\ & \\ & T_{C} = 125^{\circ}C \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ & \\ $	100A/μs, V <sub>R</sub> = 30V s, = 25°C	- - - - - - - - - - - - - - - - - - -	19         17         2.6         22         77         4.2         2.8         100         54         3.5         4.3         110         500	22 - - - - - - - - - - - - - - - - -	ns ns A nC ns A nC ns A nC

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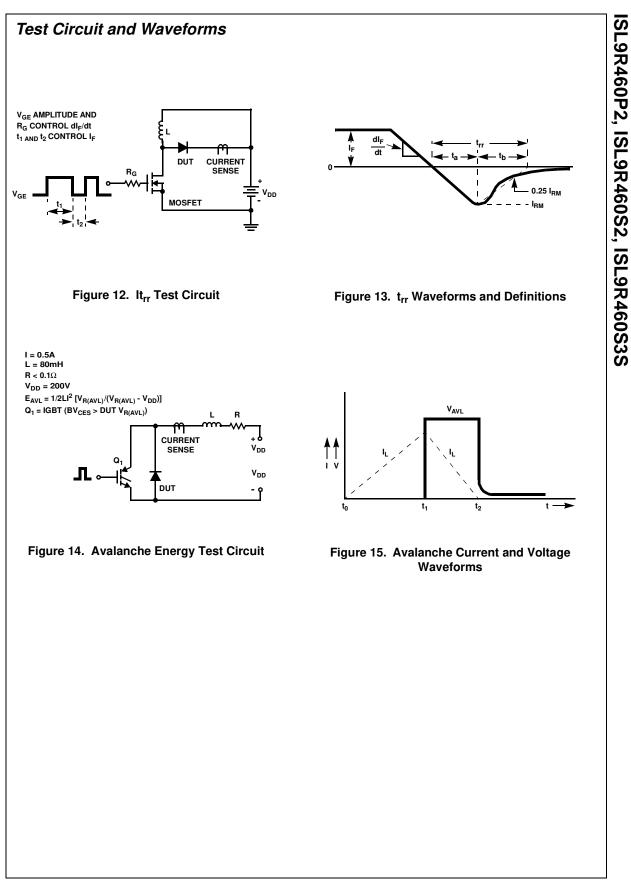
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EnSigna™	I <sup>2</sup> C™	OCX™	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
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